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## APPLICANTS

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\*\* CONTINUING DATA \*\*\*\*\* None AICS

\*\* FOREIGN APPLICATIONS \*\*\*\*\* Yes AICS  
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Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no	STATE OR	SHEETS	TOTAL	INDEPENDENT
35 USC 119 (a-d) conditions met <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance	COUNTRY	DRAWING	CLAIMS	CLAIMS
Verified and Acknowledged <i>Asitha Thirumala</i> Examiner's Signature Initials	JAPAN	8	20	3

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## TITLE

Group-III nitride semiconductor stack, method of manufacturing the same, and group-III nitride semiconductor device

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